

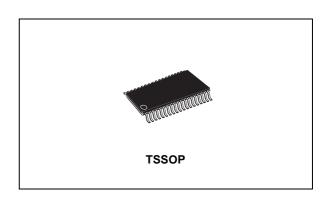
## MULTIPLE RS-232 DRIVERS AND RECEIVERS

- MEETS AND EXCEEDS THE REQUIREMENTS OF EIA/TIA-232-E AND ITUV.28 STANDARD
- SINGLE CHIP WITH EASY INTERFACE BETWEEN UART AND SERIAL PORT CONNECTOR OF IBM PC/AT<sup>TM</sup> AND COMPATIBLES
- DESIGNED TO SUPPORT DATA RATES UP TO 120 Kbps



The ST75285 contains six drivers and ten receivers. The pinout matches the DB9S connector design in order to decrease the part count, reduce the board space required and allow easy interconnection of the UART and serial port connector of IBM PC/AT<sup>TM</sup> and compatibles. The bipolar circuits and processing of the ST75285 provides a rugged low-cost solution for this function at the expense of quiescent power and external passive components relative to the ST75C185.

The ST75285 complies with the requirements of the EIA/TIA 232-E and ITU (formally CCITT) v.28 standards. These standards are for data interchange between a host computer and



peripheral at signalling rates up to 20k-bits/s. The switching speeds of the ST75285 are fast enough to support rates up to 120K-bits/s with lower capacitive loads (shorter cables). Interoperability at the higher signalling rates cannot be assured unless the designer has design control of the cable and the interface circuits at the both ends. For interoperability at signalling rates to 120 K-bits/s, use of EIA/ITA-423-B (ITU v.10) and EIA/ITA-422-B (ITU v.11) standards are recommended. It allows space saving in applications where two ST75185 are needed.

#### **ORDERING CODES**

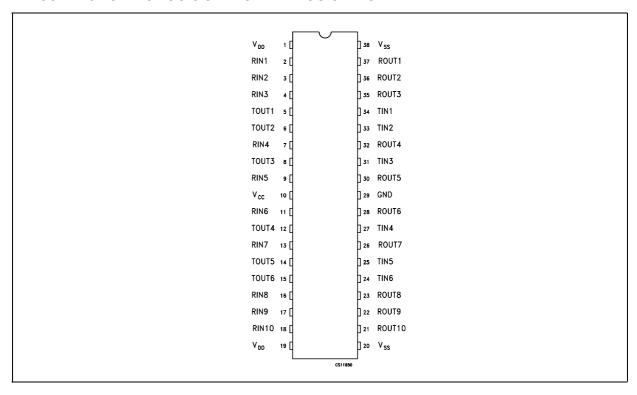
	Туре	Temperature Range	Package	Comments
ST7	'5285CTR	0 to 70 °C	TSSOP38 (Tape & Reel)	2500 parts per reel

December 2002 1/13

## **PIN DESCRIPTION**

PIN N°	SYMBOL	NAME AND FUNCTION
1	$V_{DD}$	Supply Voltage (+12V)
2	RIN1	First Receiver Input
3	RIN2	Second Receiver Input
4	RIN3	Third Receiver Input
5	TOUT1	First Driver Output
6	TOUT2	Second Driver Output
7	RIN4	Fourth Receiver Input
8	TOUT3	Third Driver Output
9	RIN5	Fifth Receiver Input
10	V <sub>CC</sub>	Supply Voltage (-12V)
11	RIN6	Sixth Receiver Input
12	TOUT4	Fourth Driver Output
13	RIN7	Seventh Receiver Input
14	TOUT5	Fifth Driver Output
15	TOUT6	Sixth Driver Output
16	RIN8	Eighth Receiver Input
17	RIN9	Nineth Receiver Input
18	RIN10	Tenth Receiver Input
19	$V_{DD}$	Supply Voltage (-12V)
20	V <sub>SS</sub>	Supply Voltage (+5V)
21	ROUT10	Tenth Receiver Ouput
22	ROUT9	Nineth Receiver Ouput
23	ROUT8	Eighth Receiver Ouput
24	TIN6	Sixth Driver Input
25	TIN5	Fifth Driver Input
26	ROUT7	Seventh Receiver Ouput
27	TIN4	Fourth Driver Input
28	ROUT6	Sixth Receiver Output
29	GND	Ground
30	ROUT5	Fifth Receiver Output
31	TIN3	Third Driver Input
32	ROUT4	Fourth Receiver Output
33	TIN2	Second Driver Input
34	TIN1	First Driver Input
35	ROUT3	Third Receiver Ouput
36	ROUT2	Second Receiver Ouput
37	ROUT1	First Receiver Ouput
38	V <sub>SS</sub>	Supply Voltage (+5V)

## PIN CONNECTION IEC LOGIC SYMBOL AND LOGIC DIAGRAM



### ABSOLUTE MAXIMUM RATINGS OVER OPERATING FREE-AIR TEMPERATURE RANGE

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	Supply Voltage (Note 1)	-0.3 to 15	V
V <sub>SS</sub>	Supply Voltage (Note 1)	0.3 to -15	V
V <sub>CC</sub>	Supply Voltage (Note 1)	-0.3 to 10	V
V <sub>I</sub>	Input Voltage Range (DRIVER)	-15 to 7	V
V <sub>I</sub>	Input Voltage Range (RECEIVER)	-30 to 30	V
V <sub>O</sub>	Output Voltage Range (DRIVER)	-15 to 15	V
Io	Receiver Low Level Output Current	20	mA
$P_{D}$	Continuous Total Power Dissipation	See dissipation Rating Table	
T <sub>A</sub>	Operating Free-Air Tempereature Range	0 to 70	°C
T <sub>stg</sub>	Storage Temperature Range	-65 to + 150	°C
ESD	Human Body Model	>2	kV
TL	Lead Temperature 1.6mm from case for 10 sec	260	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

NOTE 1: All voltage are with respect to the network ground terminal.

### DISSIPATION RATING TABLE

Package	Power Rating at T <sub>A</sub> ≤ 25°C	Derating Factor above T <sub>A</sub> = 25°C (*)	Power Rating at T <sub>A</sub> ≤ 85°C
TSSOP (T)	1277 mW	10.2 mW/°C	644 mW

<sup>(\*)</sup> This is the reverse of the traditional junction-case thermal resistance R<sub>tJ-C</sub>



## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Max	Unit
V <sub>DD</sub>	Supply Voltage		7.5	15	V
V <sub>SS</sub>	Supply Voltage		-7.5	-15	V
V <sub>CC</sub>	Supply Voltage		4.5	5.5	V
V <sub>I</sub>	Driver Input Voltage		0	V <sub>CC</sub>	V
la	High Level Output Current	DRIVER		-6	mA
Іон		RECEIVER		-0.5	IIIA
la.	Low Level Output Current	DRIVER		6	mΛ
I <sub>OL</sub>	Ī	RECEIVER		16	mA
T <sub>A</sub>	Operating Free-Air Tempereature		0	70	°C

### **SUPPLY CURRENTS**

County al	Danamatan	-	Test Cond	itions		Value		I I mit
Symbol	Parameter	V <sub>DD</sub>	V <sub>SS</sub>		Min.	Тур.	Max.	Unit
I <sub>DD</sub>	Supply Current from V <sub>DD</sub>	9	-9	No load.			22	mA
		12	-12	All inputs at			28	
		15	-15	1.9V			32	
		9	-9	No load.			9	mA
		12	-12	All inputs at			11	
		15	-15	V8.0			12	
I <sub>SS</sub>	Supply Current from V <sub>SS</sub>	9	-9	No load.			-22	mA
		12	-12	All inputs at			-28	
		15	-15	1.9V			-32	
		9	-9	No load.			-6.4	mA
		12	-12	All inputs at			-6.4	
		15	-15	0.8V			-6.4	
I <sub>CC</sub>	Supply Current from V <sub>CC</sub>	No I	oad. All inp	outs at 5V 5V			60	mA

## DRIVER ELECTRICAL CHARACTERISTICS OVER OPERATING FREE-AIR TEMPERATURE **RANGE** ( $V_{DD} = 9V$ , $V_{SS} = -9V$ , $V_{CC} = 5V$ , unless otherwise specified)

Cumbal	Davamatar	Took Conditions		Unit		
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>OH</sub>	High Level Output Voltage	$V_{IL} = 0.8 \text{ V } R_L = 3K\Omega \text{ (See Figure 1)}$	6	7.5		V
V <sub>OL</sub>	Low Level Output Voltage (Note 3)	$V_{IH} = 1.9 \text{ V } R_L = 3K\Omega \text{ (See Figure 1)}$		-7.5	-6	V
I <sub>IH</sub>	High Level Input Current	V <sub>I</sub> = 5 V (See Figure 2)			10	μΑ
I <sub>IL</sub>	Low Level Input Current	V <sub>I</sub> = 0 V (See Figure 2)			-1.6	mA
I <sub>OS(H)</sub>	High Level Short Circuit Output Current (Note 4)	$V_{IL} = 0.8 \text{ V}$ $V_O = 0 \text{ V}$ (See Figure 1)	-4.5	-12	-19.5	mA
I <sub>OS(L)</sub>	Low Level Short Circuit Output Current	$V_{IH} = 2 V$ $V_O = 0 V$ (See Figure 1)	4.5	12	19.5	mA
R <sub>O</sub>	Output Resistance	$V_{DD} = V_{SS} = V_{CC} = 0 V$ $V_{O} = -2 \text{ to } 2 \text{ V (Note 5)}$	300			Ω

NOTE 3: The algebraic convention, where the more positive (less negative) limits designated as maximum, is used in this datasheet for logic levels only (e.g. if - 10V is a maximum, the typical value is a more negative voltage).

NOTE 4: Output short circuit conditions must maintain the total power dissipation below absolute maximum ratings.

NOTE 5: Test conditions are those specified by EIA-232-E and as listed above.

## **DRIVER SWITCHING CHARACTERISTICS** ( $V_{DD} = 12V$ , $V_{SS} = -12V$ , $V_{CC} = 5V$ , $T_A = 25$ °C)

Comp. al	Dovomotov	Toot Conditions	Value			Unit
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t <sub>PLH</sub>	Propagation Delay Time, Low to High Level Output	$R_L = 3 \text{ to } 7 \text{ K}\Omega$ $C_L = 15 \text{ pF}$ (See Figure 3, 4)		200	400	ns
t <sub>PHL</sub>	Propagation Delay Time, High to Low Level Output	$R_L = 3 \text{ to } 7 \text{ K}\Omega$ $C_L = 15 \text{ pF}$ (See Figure 3, 4)		50	100	ns
t <sub>TLH</sub>	Transition Time Low to High Level Output	$R_L = 3 \text{ to } 7 \text{ K}\Omega$ $C_L = 15 \text{ pF}$ (See Figure 3, 4)		60	100	ns
		$R_L = 3 \text{ to } 7 \text{ K}\Omega$ $C_L = 2500 \text{ pF}$ (Note 6, See Figure 3, 4)		1.7	2.5	μs
t <sub>THL</sub>	Transition Time High to Low Level Output	$R_L = 3 \text{ to } 7 \text{ K}\Omega$ $C_L = 15 \text{ pF}$ (See Figure 3, 4)		50	100	ns
		$R_L = 3 \text{ to 7 K}\Omega$ $C_L = 2500 \text{ pF}$ (Note 6, See Figure 3, 4)		1.5	2.5	μs

NOTE 6: Measured between -3V and 3V points of output waveform (EIA-232-E conditions), all unused inputs are tied.

### RECEIVER ELECTRICAL CHARACTERISTICS OVER OPERATING CONDITIONS

Symbol	Parameter	Took Co	n ditions	Value			Unit
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
V <sub>T+</sub>	Positive Going Threshold Voltage	(See Figure 6)			2.2	2.4	V
V <sub>T-</sub>	Negative Going Threshold Voltage	$T_A = 25 ^{\circ}\text{C}$ (Se	e Figure 6)	0.75	0.97		V
V <sub>hys</sub>	Input Hysteresis (V <sub>T+</sub> - V <sub>T-</sub> )			0.5			V
V <sub>OH</sub>	High Level Output Voltage	$I_{OH} = -0.5 \text{mA}$	V <sub>IH</sub> = 0.75 V	2.6	4	5	V
			Inputs Open	2.6			
V <sub>OL</sub>	Low Level Output Voltage	V <sub>I</sub> = 3 V I <sub>OL</sub> =	= 10 mA		0.2	0.45	V
I <sub>IH</sub>	High Level Input Current	V <sub>I</sub> = 25 V (See	Figure 6)	3.6		8.3	mA
		V <sub>I</sub> = 3 V (See	Figure 6)	0.43			
I <sub>IL</sub>	Low Level Input Current	V <sub>I</sub> = -25 V (See	e Figure 6)	-3.6		-8.3	mA
		$V_I = -3 V$ (See	e Figure 6)	-0.43			
Ios	Short-Circuit Output Current	$V_I = 0 V V_O =$	= 0 V		-3.4	-12	mA
		(See Figure 5)					

All typical values are at TA = 25°C, VCC = 5V, VDD = 9V and VSS=-9V

# **RECEIVER SWITCHING CHARACTERISTICS** ( $V_{DD} = 12V$ , $V_{SS} = -12V$ , $V_{CC} = 5V$ $T_A = 25$ °C)

Symbol	Parameter	Test Conditions	Value			Unit
Symbol	Farameter	rest conditions	Min.	Тур.	Max.	Offic
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	$R_L = 5 \text{ K}\Omega$ $C_L = 50 \text{ pF}$ (See Figure 6)		200	500	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output	$R_L = 5 \text{ K}\Omega$ $C_L = 50 \text{ pF}$ (See Figure 6)		60	120	ns
t <sub>TLH</sub>	Transition Time Low to High Level Output	$R_L = 5 \text{ K}\Omega$ $C_L = 50 \text{ pF}$ (See Figure 6)		200	525	ns
t <sub>THL</sub>	Transition Time High to Low Level Output	$R_L = 5 \text{ K}\Omega$ $C_L = 50 \text{ pF}$ (See Figure 6)		20	60	ns

Figure 1 : Driver Test Circuit for  $V_{OH}$ ,  $I_{SO(H)}$  and  $I_{SO(L)}$ 

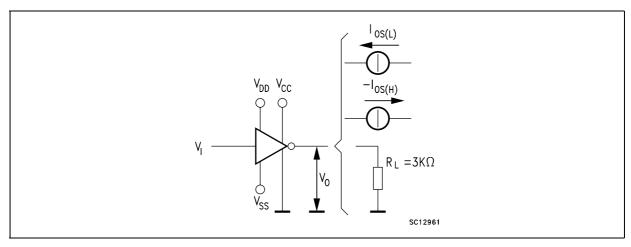


Figure 2 : Driver Test Circuit for  $\rm I_{IH}$  and  $\rm I_{IL}$ 

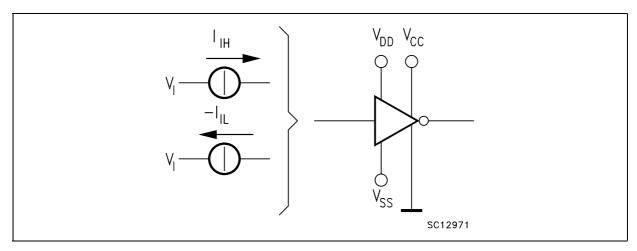


Figure 3 : Driver Test Circuit

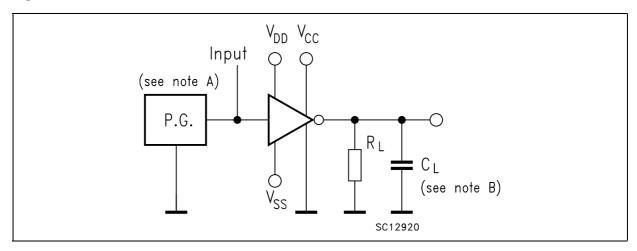


Figure 4 : Driver Voltage Waveforms

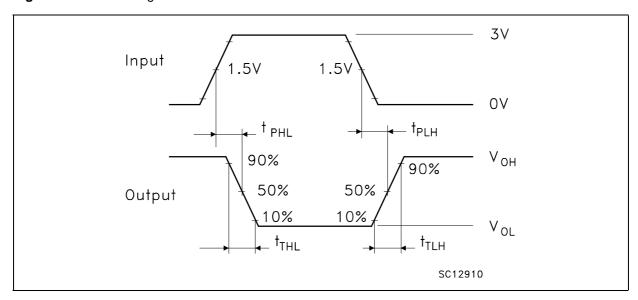
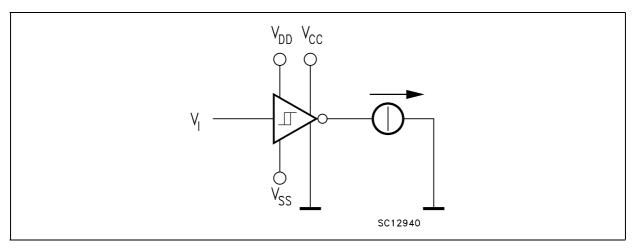


Figure 5 : Receiver Test Circuit for  $I_{OS}$ 



**Figure 6 :** Receiver Test Circuit for  $V_T$ ,  $V_{OH}$ ,  $V_{OL}$ 

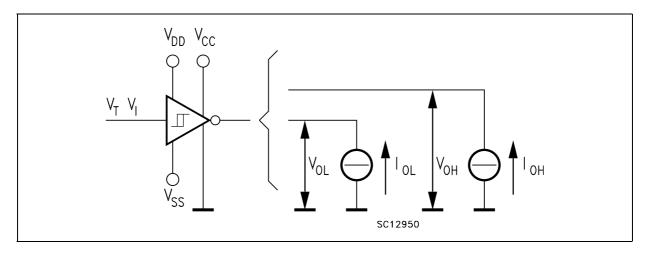


Figure 7: Receiver Test Circuit

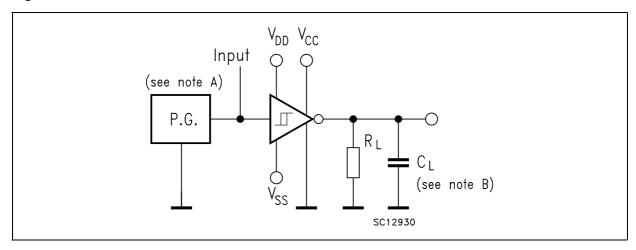
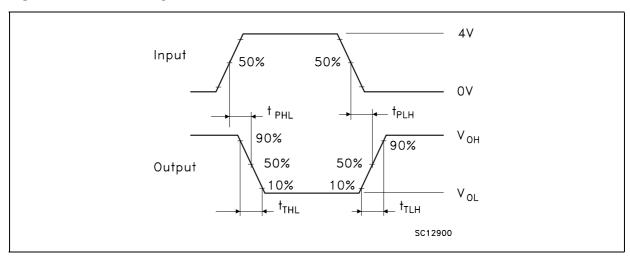
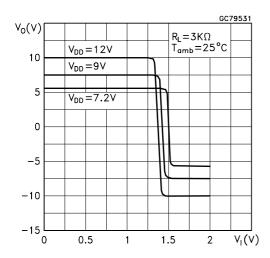


Figure 8 : Receiver Voltage Waveforms

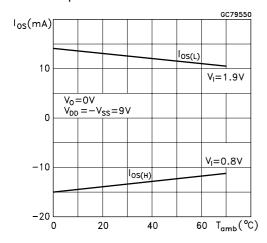


NOTE A: The pulse generator has the following characteristics:  $t_W$  = 25 $\mu$ s, PRR = 20KHz,  $Z_O$  = 50  $\Omega$ ,  $t_r$  =  $t_f$  < 50ns NOTE B:  $C_L$  includes probe and jig capacitance.

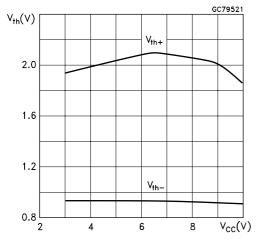
Figure 9: Driver Voltage Transfer Characteristics



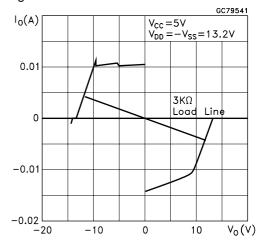
**Figure 10 :** Driver Short Circuit Output Current vs Free-Air Temperature



**Figure 11:** Receiver Threshold vs Supply Voltage



**Figure 12:** Driver Output Current vs Output Voltage



**Figure 13 :** Driver Output Slew Rate vs Load Capacitance

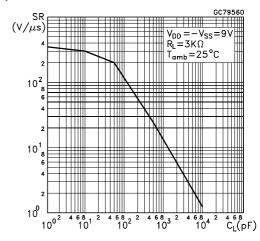
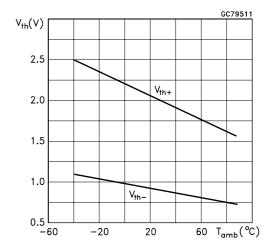
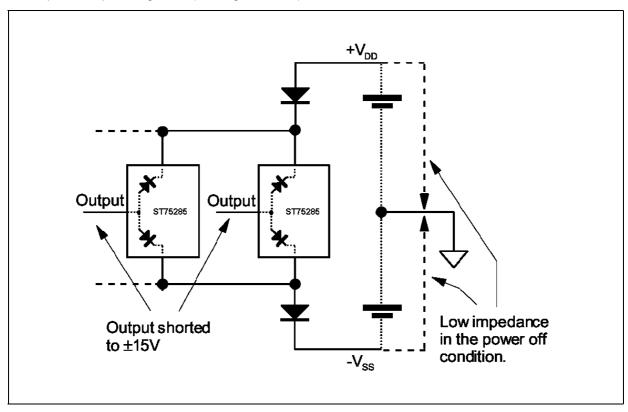


Figure 14: Receiver Threshold vs Temperature



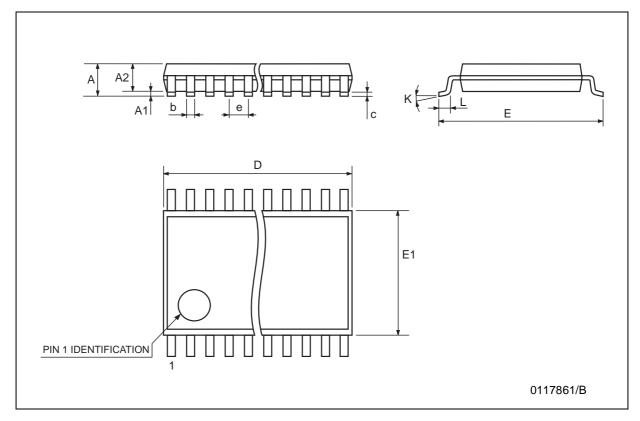
## **APPLICATION INFORMATION: DIODES ON POWER SUPPLY**

Diodes placed in series with the VDD and VSS leads protect the ST75185 in the fault condition in which the devices output are shorted to ±15V and the power supplies are at low state and provide low-impedance path to ground (see Figure below).



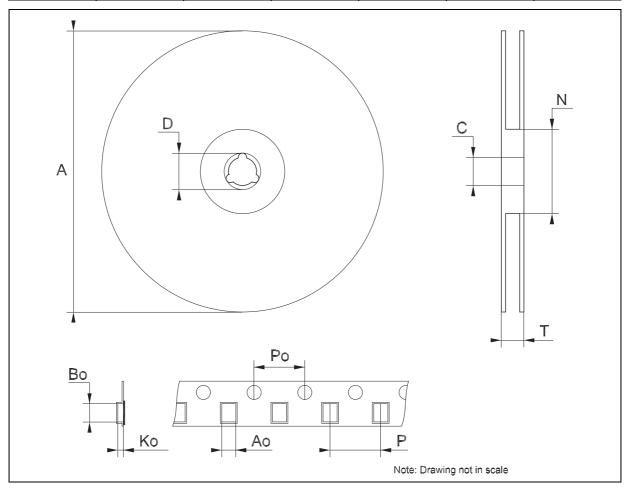
## **TSSOP38 MECHANICAL DATA**

DIM.		mm.			inch		
Diwi.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			1.2			0.047	
A1	0.05		0.15	0.002		0.006	
A2	0.8	1	1.05	0.031	0.039	0.041	
b	0.17		0.27	0.0067		0.011	
С	0.09		0.20	0.0035		0.0079	
D	9.6	9.7	9.8	0.378	0.381	0.385	
E	6.2	6.4	6.6	0.244	0.252	0.260	
E1	4.3	4.4	4.5	0.169	0.173	0.177	
е		0.5			0.0197		
K	0°		8°	0°		8°	
L	0.50	0.6	0.75	0.020	0.023	0.030	



## Tape & Reel TSSOP38 MECHANICAL DATA

DIM		mm.			inch	ıch	
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
N	60			2.362			
Т			22.4			0.882	
Ao	6.8		7	0.268		0.276	
Во	10.1		10.3	0.398		0.406	
Ko	1.7		1.9	0.067		0.075	
Po	3.9		4.1	0.153		0.161	
Р	11.9		12.1	0.468		0.476	



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

# © 2002 STMicroelectronics - Printed in Italy - All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

© http://www.st.com

